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Application of the LCAO method for energy band calculation in nanocrystals

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ABSTRACT

On the basis of the LCAO method, the energy band width of a conduction electron in a one dimensional crystal is found to be 4γ . The quantity γ is a measure of overlapping interactions among the atomic orbitals of a conduction electron. In the present work, this method is applied to a copper (f.c.c.) nanocrystal of size equal to 10a (a being the lattice constant) to see the nature of dependence of γ on the nanocrystal size. It is found that γ increases inversely as the size of nanocrystals. This agrees well with the observation that the energy band widths in nanocrystals are wider compared to those of the corresponding bulk materials.

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INTRODUCTION

According to LCAO method the energy eigen value of a conduction electron in a crystalline solid is given by[1]

$$\mathbf{E}\left(\mathbf{\bar{k}}\right) = \mathbf{E}_{0} - \alpha - \gamma \sum_{\mathbf{m}} e^{i\mathbf{\bar{k}}\cdot\left(\mathbf{\bar{R}}_{j} - \mathbf{\bar{R}}_{m}\right)}$$
(1)

 $\boldsymbol{E}_{_{0}}$ is the atomic energy, γ and α are two positive quantities defined by

$$\alpha = -\int \varphi^{\bullet} \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) V \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) \varphi \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) d\tau$$

$$\gamma = -\int \varphi^{\bullet} \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{m} \right) V' \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) \varphi \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) d\tau$$

$$V \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) \varphi \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right) d\tau$$

 $V(\vec{r} - \vec{R}_{i})$ is the lattice potential and $V'(\vec{r} - \vec{R}_{i})$ is the lattice potential minus the corresponding atomic potential experienced by a conduction electron at a position $\vec{\mathbf{r}}$ in the vicinity of the jth lattice site. The quantity α

KEYWORDS

Nanocrystals; Atomic orbital; Overlapping interaction; Energy band gap.

does not include any overlapping interaction between the atomic orbitals, while γ is a measure of the overlapping interactions.

In an f.c.c. 3D crystal, one obtains from Eq. 1 the width of an energy band given by

$$E_{bottom} = E_0 - \alpha - 12\gamma$$
$$E_{top} = E_0 - \alpha$$

Hence energy band width is

 $E_{top} - E_{bottom} = 12\gamma$ In an one dimensional crystal,^[1]

$$E_{top} = E_0 - \alpha + 2\gamma \quad \text{(for } k_x = +\frac{\pi}{a}\text{)}$$
$$E_{bottom} = E_0 - \alpha - 2\gamma \quad \text{(for } k_x = -\frac{\pi}{a}\text{)}$$

Hence energy band width is

$$E_{top} - E_{bottom} = 4\gamma$$

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Therefore, according to this model, the energy band width increases only when γ increases. With the help of some basic calculations, an attempt is made in this present work to evaluate γ for a 10a size one dimensional copper nanocrystal and then to compare the results with the already available observational data.

RESULTS AND DISCUSSION

Figure 1 depicts the evaluated atomic potential of a singly charged, i.e. monovalent copper atom. For copper, $a = 3.61 \times 10^{-10}$ m. Figure 2 essentially represents the overlapping interactions of the atomic potentials in the lattice of the cooper nanocrystal. The total lattice potential (attractive) of a 10a monovalent copper nanocrystal is given by

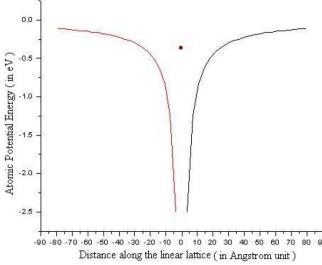


Figure 1: Atomic potential of a conduction electron with respect to a singly charged copper atom.

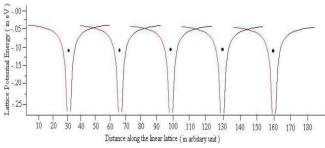


Figure 2 : Lattice potential experienced by a conduction electron in a monoatomic copper lattice. (Dots represent lattice sites)

$$V(\bar{r}) = \frac{1}{4\pi\epsilon_0} \frac{q^+ \cdot (-e)}{a} \sum_{1}^{10} \frac{1}{n} , \ \left(q^{+1} \equiv 1e\right)$$

$$= -\frac{9 \times 10^9 \times 1.6 \times 10^{-19} \times 1.6 \times 10^{-19}}{3.61 \times 10^{-10}} \times 2.98968 \quad \text{eV}$$

= -11.93 eV, (2)

= -11.93 eV,

in the unit of the dielectric constant of copper crystal ε = 1. This lattice potential is obtained by superposition of the atomic potentials corresponding to lattice site numbers 1, 2, 3,, 10 at the position of the lattice site number 1.

Let $X_1, X_2, X_3, \dots, X_{10}$ denote the lattice potential minus the corresponding atomic potential, respectively, experienced by a conduction electron when it is in the vicinity of lattice site numbers 1, 2, 3,10 in the general expression

$$\mathbf{V}'\left(\vec{\mathbf{r}}-\vec{\mathbf{R}}_{j}\right)=-\mathbf{V}\left(\vec{\mathbf{r}}\right)-\left\{\mathbf{V}\left(\vec{\mathbf{r}}-\vec{\mathbf{R}}_{j}\right)\right\}$$
(3)

It may be noted that the potential experienced by a conduction electron in the vicinity of the lattice site number 1 inside the 10a size copper nanocrystal is

$$\mathbf{V}\left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{1}\right) = \frac{1}{4\pi\varepsilon_{o}} \times \frac{(+\mathbf{q})\cdot(-\mathbf{e})}{\mathbf{a}} = -3.98 \,\mathrm{e} \,\mathrm{V} \tag{4}$$

In this calculation, it is assumed that the conduction electron is one lattice constant away from a lattice site at its nearest approach. Accordingly, under the same assumption

$$V(\vec{r} - \vec{R}_{2}) = -\frac{3.98}{2} eV, V(\vec{r} - \vec{R}_{3}) = -\frac{3.98}{3} eV,$$

....., $V(\vec{r} - \vec{R}_{10}) = -\frac{3.98}{10} eV$ (5)

It is seen that when a conduction electron approaches a positively charged lattice site to a distance

TABLE 1 : Evaluated values of X.

X _n	in eV
X _{1/4}	-3.99
X _{1/2}	+3.97
X_1	+7.946
X_2	+10.231
X_3	+10.599
X_4	+10.931
X_5	+11.13
X_6	+11.26
X_7	+11.357
X_8	+11.4285
X_9	+11.483
X_{10}	+11.528

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of a/2.997, $V'(\vec{r} - \vec{R}_{j})$ becomes equal to zero. As shown in TABLE 1 at a distance of approach equal to a/4, $V'(\vec{r} - \vec{R}_{j})$ becomes negative, which implies a repulsive potential in the scheme of energy measurement as explained here after.

With respect to some suitably assigned reference level of energy measurement (which is taken to be the $V(\vec{r})=0$ level), it is seen from Figures 1 and 2 and also from Eqs. 2, 3, 4, 5 that as the number of lattice sites in the nanocrystal increases, the corresponding lattice potential approaches the reference level { $V(\vec{r})=0$ } progressively. In this scheme of energy measurement, the lattice potential $V(\vec{r} - \vec{R}_j)$ is less than $V(\vec{r})$ for all values of the lattice site number j. In the stated scheme of energy measurement, the Eq. 3 should be rewritten as

$$V'(\vec{r} - \vec{R}_{j}) = V(\vec{r}) - V(\vec{r} - \vec{R}_{j})$$

= X_n (6)

Keeping this consideration in mind, the values of X_n except that for $X_{1/4}$ become positive. In TABLE 1, the values of X_n are listed.

It is pertinent to consider the atomic orbitals in their ground state. The orbitals corresponding to a singly ionized copper atom are similar to Hydrogen atom orbitals. These are given by reference^[2]

$$\varphi(\vec{\mathbf{r}}) = \mathbf{e}^{-\frac{1}{2}\vec{\mathbf{r}}} \vec{\mathbf{r}}^{1} \mathbf{L}_{n+1}^{2l+1}(\vec{\mathbf{r}})$$

where the different symbols have their usual significance. Hence

$$\gamma = -\int \!\! \left[\left\{ e^{-\frac{1}{2}\vec{r}} \; \vec{r}^1 \; L_{n+1}^{2l+1}\!\left(\!\vec{r}\right) \!\! \right\}^{\bullet} V'\!\left(\!\vec{r} - \vec{R}_j\right) \!\! \left\{ e^{-\frac{1}{2}\vec{r}} \; \vec{r}^1 \; L_{n+1}^{2l+1}\!\left(\!\vec{r}\right) \!\! \right\} \right] \! d\tau$$

And the value of the normalization integral is

$$\int_{0}^{\infty} e^{-\vec{r}} \vec{r}^{2l} \left[L_{n+1}^{2l+1}(\vec{r}) \right]^{2} \vec{r}^{2} d\mathbf{r} = \frac{2n \left[(n+1)! \right]^{3}}{(n-l-1)!}$$

For an s orbital (l=0)

 $\frac{2n[(n+1)!]^3}{(n-1-1)!} = 2$, for n = 1 i.e. ground state orbitals.

Hence
$$\gamma = -2V' \left(\vec{\mathbf{r}} - \vec{\mathbf{R}}_{j} \right)$$
 (7)

It may be noted that in the first approximation, effect of all the overlapping interactions is included in $V'(\vec{r} - \vec{R}_j)$ only, and in the light of this approximation, the normal-

ization integral is taken to be independent of $V'(\vec{r} - \vec{R}_{i})$.

In TABLE 2 the evaluated values of γ for different nanocrystal sizes containing 2 lattice sites, 3 lattice sites, 4 lattice sites,up to 10 lattice sites, are given.

TABLE 2 : Evaluated values of γ_n .

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$\gamma_n = -2X_n$	in eV
$\gamma_{1/4}$	+7.98
$\gamma_{1/2}$	- 7.94
γ_1	-15.892
γ_2	-20.462
γ_3	-21.198
γ_4	-21.862
γ_5	-22.26
γ_6	-22.52
γ_7	-22.714
γ_8	-22.857
γ9	-22.966
γ_{10}	-23.056

Figure 3 shows the variation of the evaluated γ with nanocrystal sizes. It is quite evident from Figure 3 that as the crystal size decreases the corresponding γ value increases. Hence the energy band width (= 4 γ for a one dimensional Cu nanocrystal) is a function of the size of the nano crystal. To be specific, the band width increases as the size of the nanocrystal decreases. This gives a new approach of theoretical support to the observation that the energy band gap in a nano crystal is inversely proportional to its size^[3]. Thus it is seen that the LCAO method can also be applied to the band

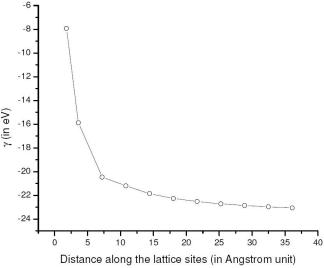


Figure 3 : Dependence of γ on size of copper nanocrystal.

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structure studies of nano crystals. Further studies in this line have potential merits.

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